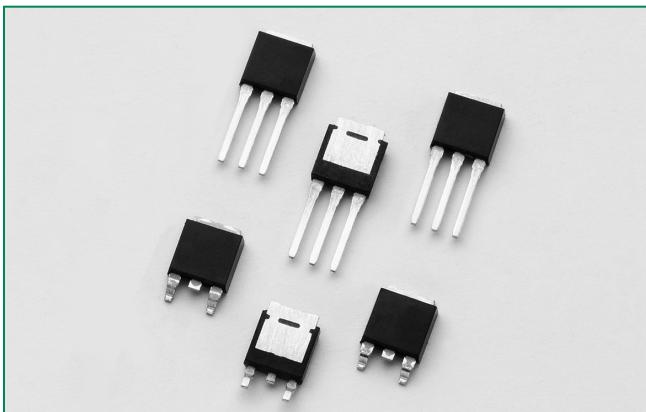


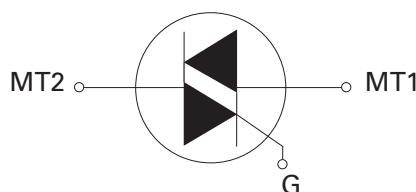
LJxx06xx & QJxx06xHx series

Main Features

Symbol	Value	Unit
I_{TRMS}	6	A
V_{DRM}/V_{RRM}	400 or 600	V
$I_{GT(Q1)}$	10 to 35	mA

Schematic Symbol



PRELIMINARY & CONFIDENTIAL

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Description

This 6 A High Temperature Alternistor Triac solid state switch series is designed for AC switching and phase control applications such as motor speed and temperature modulation controls, lighting controls, and static switching relays.

Sensitive type components guarantee gate control in Quadrants I & IV needed for digital control circuitry.

Alternistor type components only operate in quadrants I, II, & III and are used in circuits requiring high dv/dt capability.

Features & Benefits

- ~~RoHS compliant~~
- 150°C maximum junction temperature
- Voltage capability up to 600V
- Surge capability up to 72A at 60Hz half cycle
- Solid-state switching eliminates arcing or contact bounce that create voltage transients
- No contacts to wear out from reaction of switching events
- Restricted (or limited) RFI generation, depending on activation point of sine wave
- Requires only a small gate activation pulse in each half-cycle
- Halogen free and RoHS compliant

Applications

Excellent for AC switching and phase control applications such as heating, lighting, and motor speed controls.

Typical applications are AC solid-state switches, light dimmers, power tools, home/brown goods and white goods appliances.

Alternistor Triacs (no snubber required) are used in applications with high inductive loads requiring the highest commutation performance.

Internally constructed isolated packages are offered for ease of heat sinking with highest isolation voltage.

Absolute Maximum Ratings — Sensitive Triac (4 Quadrants)

Symbol	Parameter	Value	Unit
V_{DSM}/V_{RSM}	Peak non-repetitive blocking voltage	700	V
I_{TRMS}	RMS on-state current (full sine wave)	6	A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_J initial = 25°C)	60	A
I^2t	I^2t Value for fusing	72	A
di/dt	Critical rate of rise of on-state current $I_G = 50\text{mA}$ with 0.1 μs rise time	21.5	A ^2s
I_{GTM}	Peak gate trigger current	70	A/ μs
$P_{G(AV)}$	Average gate power dissipation	0.4	W
T_{stg}	Storage temperature range	-40 to 150	°C
T_J	Operating junction temperature range	-40 to 150	°C

Note: xx=voltage/10, y = sensitivity

Absolute Maximum Ratings — Alternistor Triac (3 Quadrants)

Symbol	Parameter				Value	Unit		
$V_{DSM}V_{RSM}$	Peak non-repetitive blocking voltage				700	V		
I_{TRMS}	RMS on-state current (full sine wave)		$QJxx06VHy/QJxx06DHy$		$T_c = 130^\circ\text{C}$	A		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)		$f = 50 \text{ Hz}$	$t = 20 \text{ ms}$	$QJxx06VHy$ $QJxx06DHy$	60		
			$f = 60 \text{ Hz}$	$t = 16.7 \text{ ms}$	$QJxx06VHy$ $QJxx06DHy$	72		
I^2t	I^2t Value for fusing		$t_p = 8.3 \text{ ms}$		$QJxx06VHy$ $QJxx06DHy$	$21.5 \text{ A}^2\text{s}$		
di/dt	Critical rate of rise of on-state current		$f = 60 \text{ Hz}$		$T_j = 150^\circ\text{C}$	$70 \text{ A}/\mu\text{s}$		
I_{GTM}	Peak gate trigger current		$t_p \leq 10 \mu\text{s}; I_{GT} \leq I_{GTM}$		$T_j = 150^\circ\text{C}$	A		
$P_{G(AV)}$	Average gate power dissipation				$T_j = 150^\circ\text{C}$	0.3 W		
T_{stg}	Storage temperature range				-40 to 150			
T_j	Operating junction temperature range				-40 to 150			

Note: xx=voltage/10, y = sensitivity

Electrical Characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified) — Sensitive Triac (4 Quadrants)

Symbol	Test Conditions	Quadrant		Value LJxx06x8	Unit	
		I - II - III	IV			
I_{GT}	$V_D = 12\text{V}$ $R_L = 60 \Omega$	MAX.	MAX.	10 20	mA	
		ALL	MAX.	1.2	V	
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 150^\circ\text{C}$	ALL	MIN.	0.15	V	
I_H	$I_T = 100\text{mA}$	MAX.		25	mA	
dv/dt	$V_D = V_{DRM}$ Gate Open $T_j = 150^\circ\text{C}$	400V	TYP.	80	$\text{V}/\mu\text{s}$	
		600V		50		
$(dv/dt)c$	$(di/dt)c = 3.2 \text{ A}/\text{ms}$ $T_j = 150^\circ\text{C}$	TYP.		2	$\text{V}/\mu\text{s}$	
t_{gt}	$I_G = 2 \times I_{GT}$ $PW = 15\mu\text{s}$ $I_T = 8.5 \text{ A(pk)}$	TYP.		12	μs	

Note: xx=voltage/10, x = package

Electrical Characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified) — Alternistor Triac (3 Quadrants)

Symbol	Test Conditions	Quadrant		Value		Unit
		QJxx06xH3	QJxx06xH4			
I_{GT}	$V_D = 12\text{V}$ $R_L = 60 \Omega$	I - II - III	MAX.	10	35	mA
		I - II - III	MAX.	1.3		V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 150^\circ\text{C}$	I - II - III	MIN.	0.15		V
I_H	$I_T = 100\text{mA}$	MAX.		25	35	mA
dv/dt	$V_D = V_{DRM}$ Gate Open $T_j = 150^\circ\text{C}$	QJxx06VHY/ QJxx06DHY	MIN.	400V	150	350
				600V	100	250
$(dv/dt)c$	$(di/dt)c = 3.2 \text{ A}/\text{ms}$ $T_j = 150^\circ\text{C}$	MIN.		15	20	$\text{V}/\mu\text{s}$
t_{gt}	$I_G = 2 \times I_{GT}$ $PW = 15\mu\text{s}$ $I_T = 8.5 \text{ A(pk)}$	TYP.		10	10	μs

Note: xx=voltage/10, x = package

Thyristors

6 Amp High Temp Sensitive & Alternistor (High Commutation) Triacs

Static Characteristics

Symbol	Test Conditions				Value	Unit		
V_{TM}	$I_{TM} = 8.4 \text{ A}$ $t_p = 380 \mu\text{s}$ $V_{DRM} = V_{RRM}$	LJxx06xy	$T_J = 25^\circ\text{C}$	400 - 600V	MAX.	1.40		
I_{DRM} / I_{RRM}			$T_J = 125^\circ\text{C}$	400 - 600V		10 μA		
			$T_J = 150^\circ\text{C}$	400 - 600V		0.5 mA		
QJxx06xHy		$T_J = 25^\circ\text{C}$	400 - 600V	3 mA				
		$T_J = 125^\circ\text{C}$	400 - 600V	10 μA				
		$T_J = 150^\circ\text{C}$	400 - 600V	0.5 mA				
				3 mA				

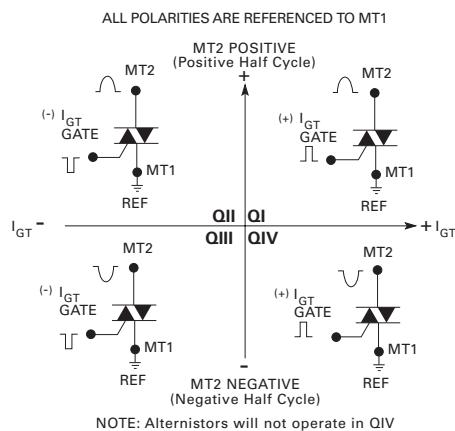
Note: xx=voltage/10, x = package, y = sensitivity

Thermal Resistances

Symbol	Parameter	Value	Unit
$R_{\theta(JC)}$	Junction to case (AC)	LJ/QJxx06Vyy LJ/QJxx06Dyy	1.3 $^\circ\text{C}/\text{W}$
$R_{\theta(J-A)}$	Junction to ambient	LJ/QJxx06Vyy LJ/QJxx06Dyy	70 $^\circ\text{C}/\text{W}$

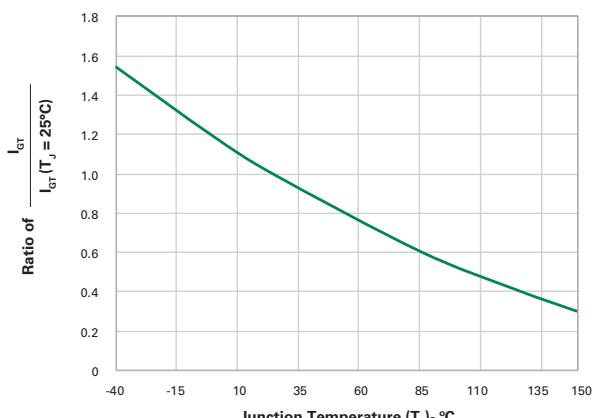
Note: xx=voltage/10, y = sensitivity

Figure 1: Definition of Quadrants



Note: Alternistors will not operate in QIV

Figure 2: Normalized DC Gate Trigger Current for All Quadrants vs. Junction Temperature



PRELIMINARY & CONFIDENTIAL

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Thyristors

6 Amp High Temp Sensitive & Alternistor (High Commutation) Triacs

Figure 3: Normalized DC Holding Current vs. Junction Temperature

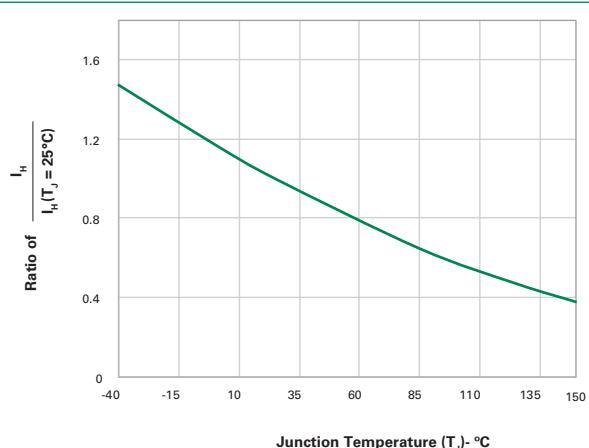


Figure 4: Normalized DC Gate Trigger Voltage for All Quadrants vs. Junction Temperature

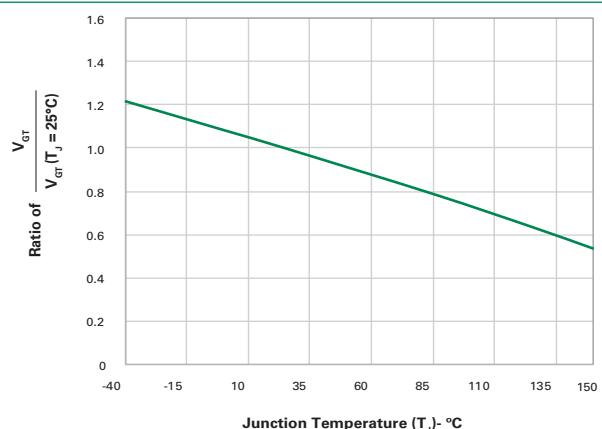


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

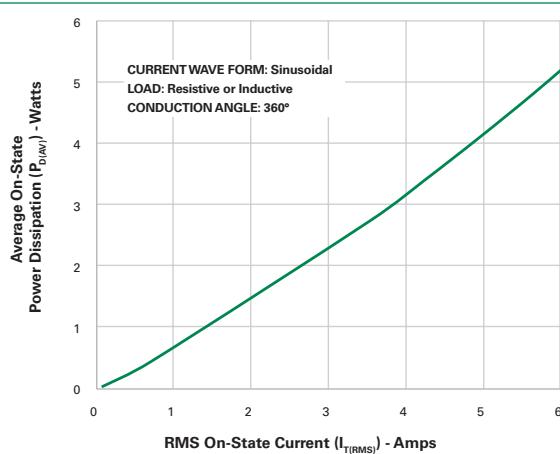


Figure 6: Maximum Allowable Case Temperature vs. On-State Current

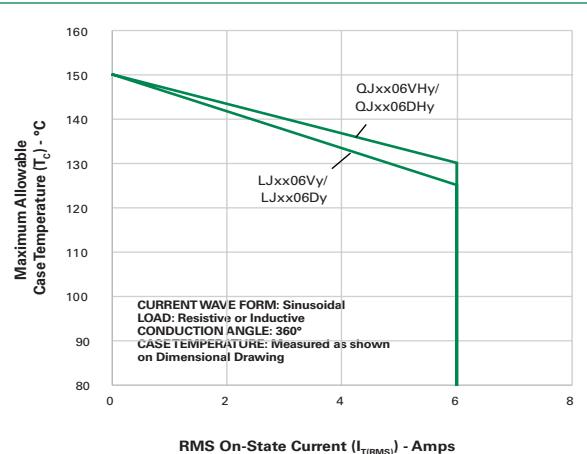
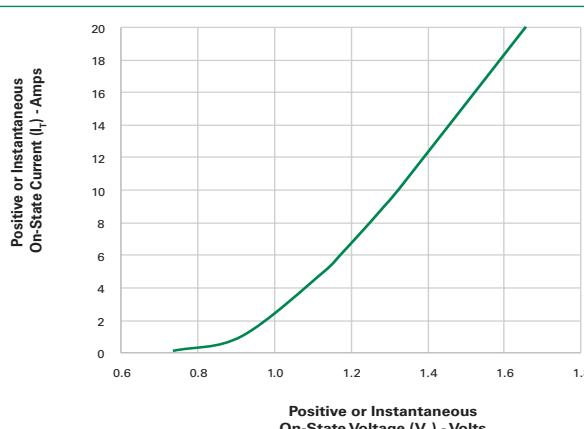


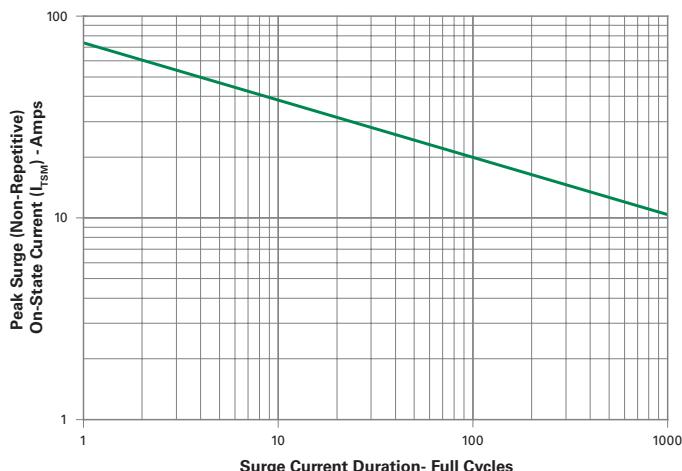
Figure 7: On-State Current vs. On-State Voltage (Typical)



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Figure 8: Surge Peak On-State Current vs. Number of Cycles



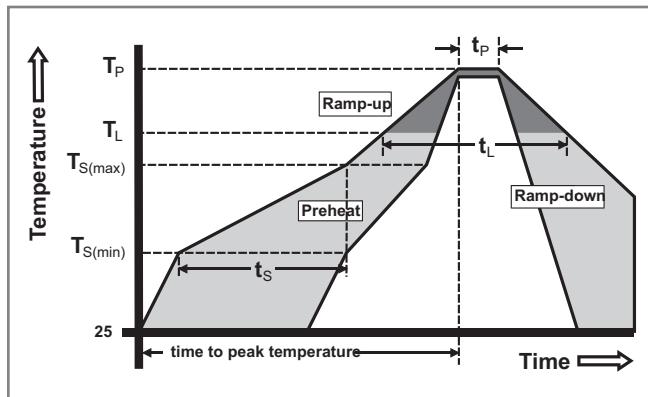
SUPPLY FREQUENCY: 60 Hz Sinusoidal
 LOAD: Resistive
 RMS On-State Current: I_{TIRMS} : Maximum Rated Value at Specified Case Temperature

Notes:

1. Gate control may be lost during and immediately following surge current interval.
2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
Reflow	$T_{S(max)}$ to T_L - Ramp-up Rate	5°C/second max
	- Temperature (T_L) (Liquidus)	217°C
	- Time (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		280°C



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Physical Specifications

Terminal Finish	100% Matte Tin-plated
Body Material	UL recognized compound meeting flammability rating V-0.
Terminal Material	Copper Alloy

Environmental Specifications

Test	Specifications and Conditions
AC Blocking (V_{DRM})	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 150°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -55°C to +150°C; 15-min dwell-time
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 160V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E

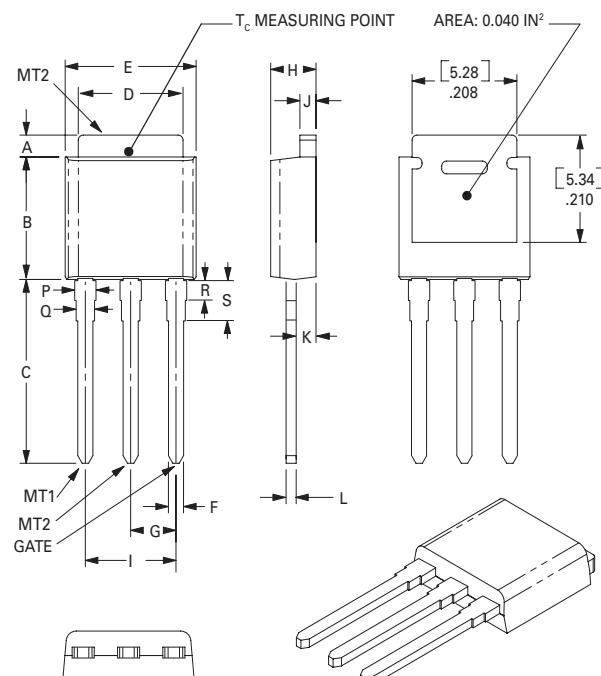
Design Considerations

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

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Dimensions – TO-251AA (V-Package) – V-PAK Through Hole

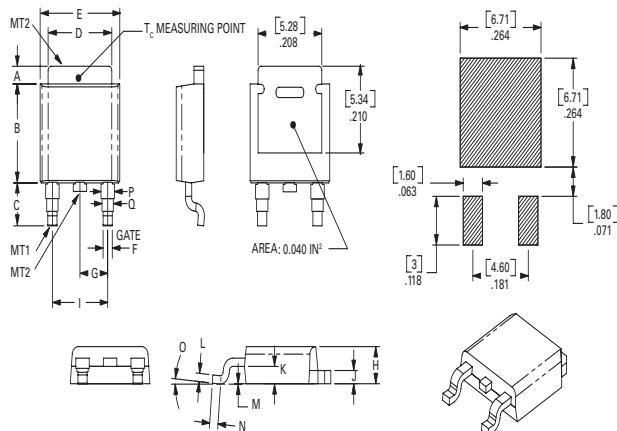


Dimension	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.037	0.040	0.043	0.94	1.01	1.09
B	0.235	0.242	0.245	5.97	6.15	6.22
C	0.350	0.361	0.375	8.89	9.18	9.53
D	0.205	0.208	0.213	5.21	5.29	5.41
E	0.255	0.262	0.265	6.48	6.66	6.73
F	0.027	0.031	0.033	0.69	0.80	0.84
G	0.087	0.090	0.093	2.21	2.28	2.36
H	0.085	0.092	0.095	2.16	2.34	2.41
I	0.176	0.180	0.184	4.47	4.57	4.67
J	0.018	0.020	0.023	0.46	0.51	0.58
K	0.035	0.037	0.039	0.90	0.95	1.00
L	0.018	0.020	0.023	0.46	0.52	0.58
P	0.042	0.047	0.052	1.06	1.20	1.32
Q	0.034	0.039	0.044	0.86	1.00	1.11
R	0.034	0.039	0.044	0.86	1.00	1.11
S	0.074	0.079	0.084	1.86	2.00	2.11

Thyristors

6 Amp High Temp Sensitive & Alternistor (High Commutation) Triacs

Dimensions — TO-252AA (D-Package) — D-PAK Surface mount



Dimension	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.037	0.040	0.043	0.94	1.01	1.09
B	0.235	0.243	0.245	5.97	6.16	6.22
C	0.106	0.108	0.113	2.69	2.74	2.87
D	0.205	0.208	0.213	5.21	5.29	5.41
E	0.255	0.262	0.265	6.48	6.65	6.73
F	0.027	0.031	0.033	0.69	0.80	0.84
G	0.087	0.090	0.093	2.21	2.28	2.36
H	0.085	0.092	0.095	2.16	2.33	2.41
I	0.176	0.179	0.184	4.47	4.55	4.67
J	0.018	0.020	0.023	0.46	0.51	0.58
K	0.035	0.037	0.039	0.90	0.95	1.00
L	0.018	0.020	0.023	0.46	0.51	0.58
M	0.000	0.000	0.004	0.00	0.00	0.10
N	0.021	0.026	0.027	0.53	0.67	0.69
O	0°	0°	5°	0°	0°	5°
P	0.042	0.047	0.052	1.06	1.20	1.32
Q	0.034	0.039	0.044	0.86	1.00	1.11

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Product Selector

Part Number	Voltage		Gate Sensitivity Quadrants		Type	Package
	400V	600V	I - II - III	IV		
LJxx06D8	x	x	10	20	Sensitive Triac	TO-252 D-PAK
LJxx06V8	x	x	10	20	Sensitive Triac	TO-251 V-PAK
QJxx06DH3	x	x	10		Alternistor Triac	TO-252 D-PAK
QJxx06VH3	x	x	10		Alternistor Triac	TO-251 V-PAK
QJxx06DH4	x	x	35		Alternistor Triac	TO-252 D-PAK
QJxx06VH4	x	x	35		Alternistor Triac	TO-251 V-PAK

Note: xx = voltage/10

Packing Options

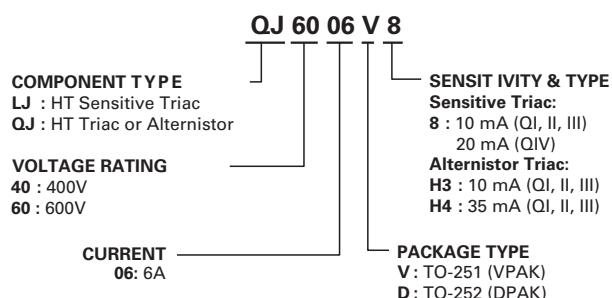
Part Number	Marking	Weight	Packing Mode	Base Quantity
LJxx06D8TP	LJxx06D8	0.3g	Tube Pack	750(75 per tube)
LJxx06D8RP	LJxx06D8	0.3g	Embossed Carrier	2500
LJxx06V8TP	LJxx06V8	0.4g	Tube Pack	750(75 per tube)
QJxx06DH3TP	QJxx06DH3	0.3g	Tube Pack	750(75 per tube)
QJxx06DH3RP	QJxx06DH3	0.3g	Embossed Carrier	2500
QJxx06VH3TP	QJxx06VH3	0.4g	Tube Pack	750(75 per tube)
QJxx06DH4TP	QJxx06DH4	0.3g	Tube Pack	750(75 per tube)
QJxx06DH4RP	QJxx06DH4	0.3g	Embossed Carrier	2500
QJxx06VH4TP	QJxx06VH4	0.4g	Tube Pack	750(75 per tube)

Note: xx = voltage/10

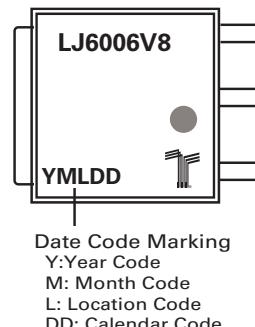
Thyristors

6 Amp High Temp Sensitive & Alternistor (High Commutation) Triacs

Part Numbering System

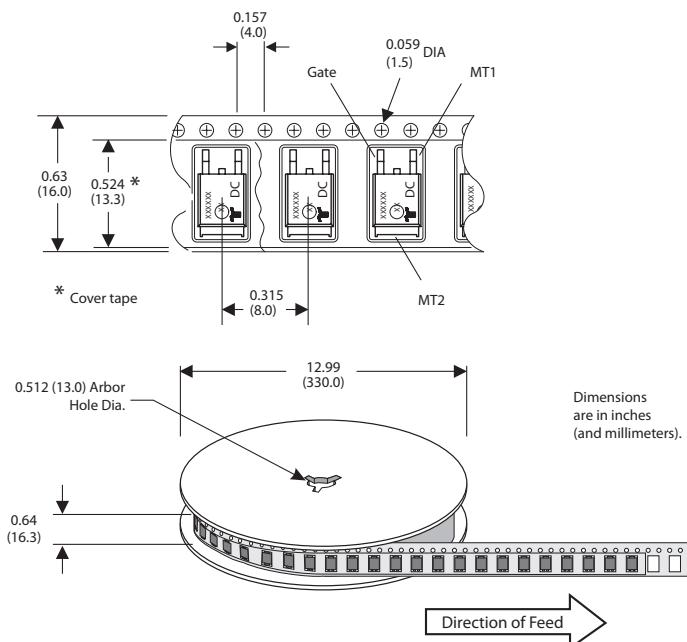


Part Marking System



TO-252 Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-481-2 Standards



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